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NEPRT-86-2024

FACULTY OF SCIENCE

M.Sc. (NEP) (First Year) (First Semester) EXAMINATION APRIL/MAY, 2024

PHYSICS

(SPHYE-401)

(Electronic Devices)

(Tuesday, 30-04-2024) Time: 10.00 a.m. to 12.30 p.m.				
\overline{Time}	-2½ <i>F</i>	Hours Maximum Mark	s—60	
N.B.	: (i)	All questions carry equal marks.		
	(ii)	Question No. 1 is compulsory.		
		Solve any <i>three</i> of the remaining five questions (Q. Nos. 2 to Figures to the right indicate full marks.	6).	
1.		the following questions (each question 5 marks):	15	
	(a) _	Explain p and n-type semiconductor.		
	(b)	Explain working of LED.		
	(c)	State characteristics of ideal Op-Amp.		
2.	(a) _	Explain input and output characteristics of NPN transistor.	8	
	(b)	Explain principle and working of JFET.	7	
3.	(a)	Explain working and applications of photodiodes.	8	
	(b)	What are direct and indirect band gap semiconductor? Expla	ain in	
		brief.	7	
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4.	(a)	Explain, how Op-amp can be used as non-inverting amplifier and give
		the equation of voltage gain.
	(<i>b</i>)	Draw the circuit diagram for Op-amp used as adder. Explain its working
		and derive equation for output voltage.
5.	(a)	Explain binary addition and substraction with suitable example. 8
	(<i>b</i>)	Draw the symbols and truth tables for AND, OR and NOT
		gates.
6.	Write	short notes on (each question 5 marks):
	(a)	UJT (Uni-junction transistors)
	(b)	Differential amplifier.
	(c)	Exclusive OR gate (Ex-OR)